Listing of Claims:

(Claims 1-25 have been cancelled.)

- 26. (Original) In a non-volatile memory system including a plurality of bit lines oriented to cross a plurality of word lines with inductive coupling therebetween, a method of applying a voltage pulse to at least one selected bit line, comprising setting the rate of rise of said voltage pulse to control a level of current induced in at least one word line.
- 27. (Original) A method of operating a non-volatile memory, said non-volatile memory comprising:

a plurality of word lines;

a plurality of bit lines, at least some of the plurality of bit lines being inductively coupled with at least a group of the plurality of word lines; and

a plurality of non-volatile memory cells individually connected to at least one of the bit lines and to one of the word lines;

wherein data are simultaneously written into at least a given number of the plurality of cells that are connected to at least one selected of said group of word lines in a programming operation that applies a first voltage to the selected word line, a second voltage to at least some of the plurality of bit lines to which said given number of cells are connected, and a reference voltage to others of said group of word lines that are not selected;

said method comprising performing said programming operation by applying a pulse of the second voltage to at least some of the plurality of bit lines to which said given number of cells are connected in a manner to avoid disturbing data stored in those of the memory cells connected to said others of said word lines that are not selected.

- 28. (Original) The method of claim 27, wherein a ramp rate of a leading edge of said voltage pulse is selected to control the amount of voltage that is induced thereby into said others of the word lines that are not selected.
- 29. (Original) The method of claim 27, wherein a number of the plurality of bit lines receiving the pulse of the second voltage is less than those which could simultaneously receive said pulse to carry out the programming operation.

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